

PW1012

20V N-Channel MOSFET

500mA 20V; $R_{DS(ON)typ}=190m\Omega@4.5V$, $R_{DS(ON)typ}=260m\Omega@2.5V$

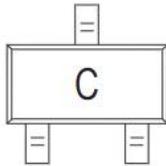
FEATURE

- High-Side Switching
- Low On-Resistance
- Low Threshold
- Fast Switching Speed
- ESD Protected

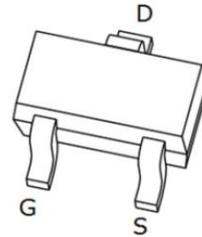
Application

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- Battery Operated Systems
- Power Supply Converter Circuits
- Load/Power Switching Cell Phones, Pagers

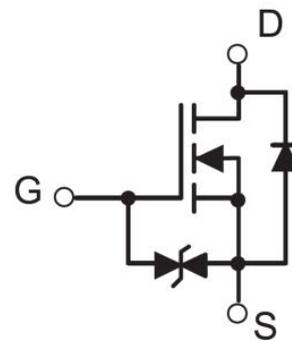
MARKING:



SOT-523



Schematic diagram



ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 12	
Continuous Drain Current	I_D	500	mA
Pulsed Drain Current ¹	I_{DM}	1000	
Power Dissipation ²	P_D	150	mW
Maximum Power Dissipation ³		275	
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	833	$^{\circ}C/W$
Junction Temperature	T_J	150	$^{\circ}C$
Storage Temperature	T_{STG}	-55~+150	

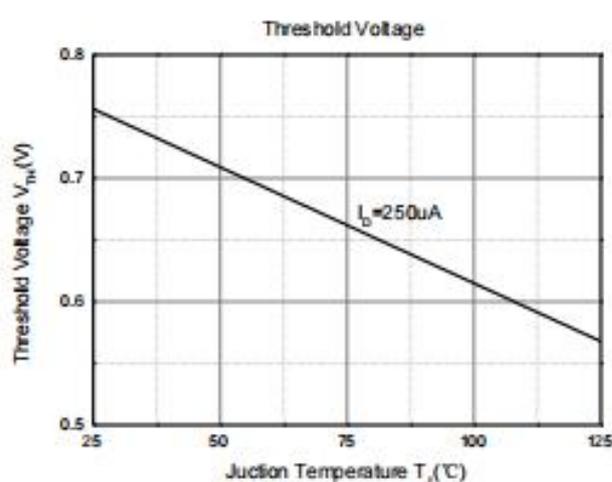
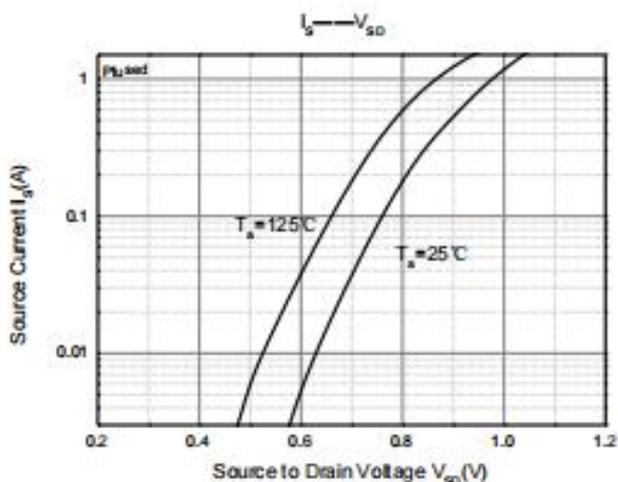
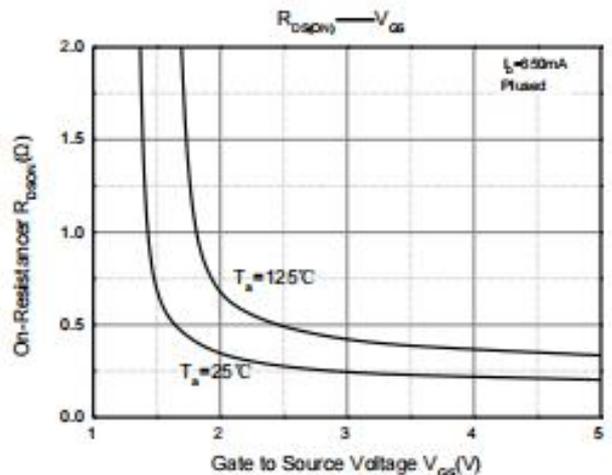
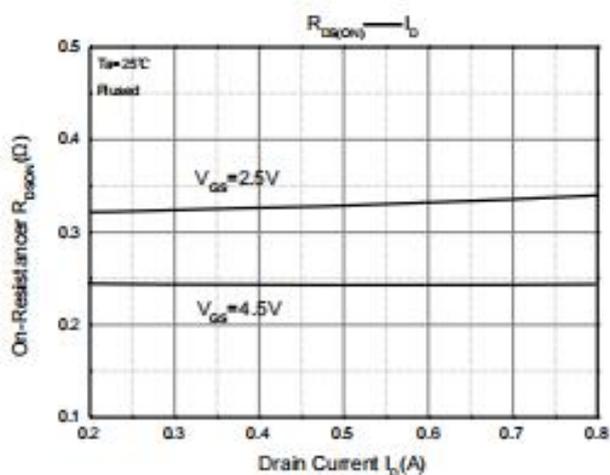
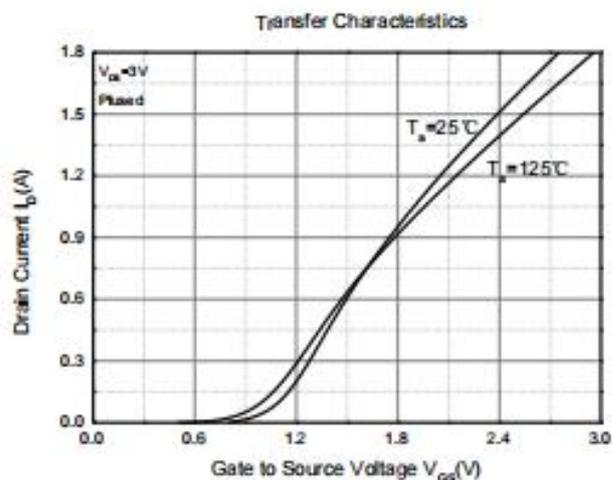
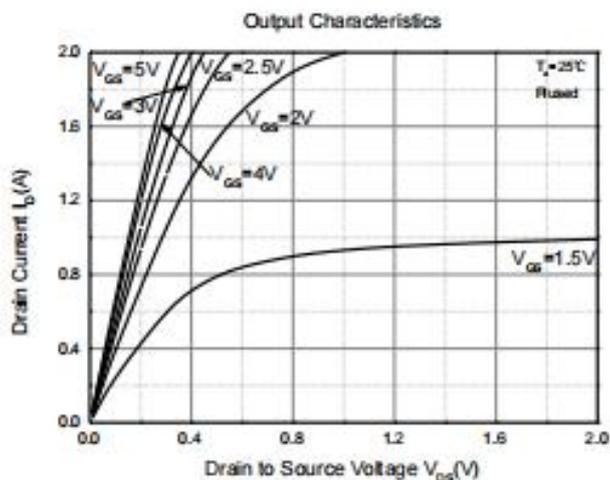
MOSFET ELECTRICAL CHARACTERISTICS(T_a=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Type	Max	Unit
STATIC CHARACTERISTICS						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =250μA	20			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =16V,V _{GS} = 0V			1	μA
Gate-body leakage current	I _{GSS}	V _{GS} =±4.5V, V _{DS} = 0V			±1	μA
Gate threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.45	0.8	1.2	V
Drain-source on-resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =600mA		190	250	mΩ
		V _{GS} =2.5V, I _D =500mA		260	340	
Forward tranconductance	g _{FS}	V _{DS} =10V, I _D =400mA	1			S
DYNAMIC CHARACTERISTICS⁴						
Input Capacitance	C _{iss}	V _{DS} =16V,V _{GS} =0V,f=1MHz			120	pF
Output Capacitance	C _{oss}				20	
Reverse Transfer Capacitance	C _{rss}				15	
SWITCHING CHARACTERISTICS⁴						
Turn-on delay time	t _{d(on)}	V _{DD} =10V,I _D =500mA, V _{GS} =4.5V,R _G =10Ω		6.7		ns
Turn-on rise time	t _r			4.8		
Turn-off delay time	t _{d(off)}			17.3		
Turn-off fall time	t _f			7.4		
SOURCE-DRAIN DIODE CHARACTERISTICS						
Diode Forward voltage ⁵	V _{DS}	I _S =0.15A, V _{GS} = 0V			1.2	V

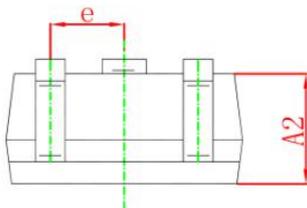
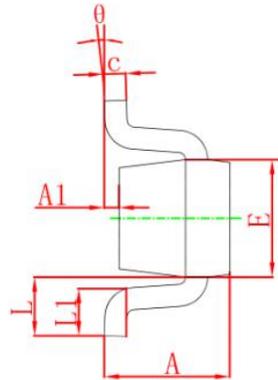
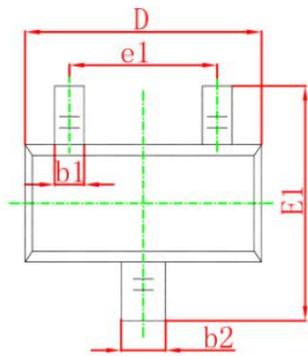
Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. This test is performed with no heat sink at T_a=25°C.
3. This test is performed with infinite heat sink at T_c=25°C.
4. These parameters have no way to verify.
5. Pulse Test : Pulse Width≤300μs, Duty Cycle≤0.5%.

Typical Electrical and Thermal Characteristics



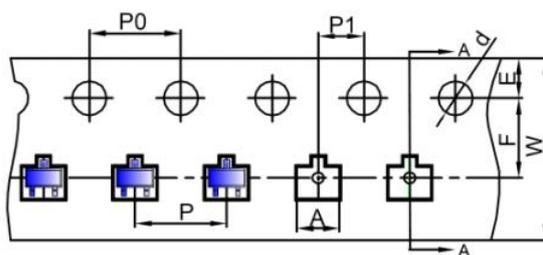
SOT-523 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500 TYP.		0.020 TYP.	
e1	0.900	1.100	0.035	0.043
L	0.400 REF.		0.016 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

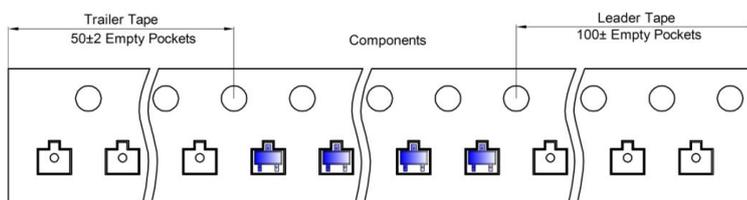
SOT-523 Tape and Reel

SOT-523 Embossed Carrier Tape

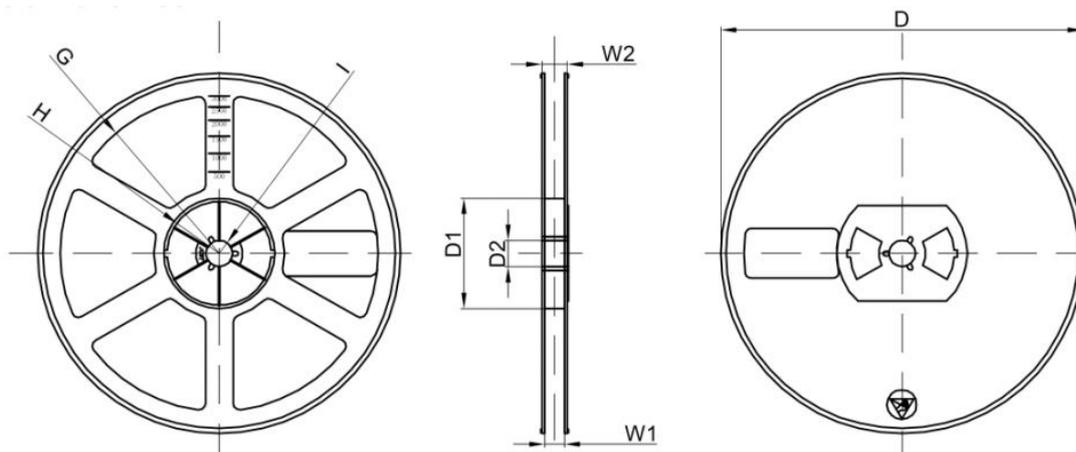


Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-523	1.85	1.85	0.875	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-523 Tape Leader and Trailer



SOT-523 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	